



SANYO Semiconductors

# DATA SHEET

## STK404-070S — Thick-Film Hybrid IC One-Channel Class AB Audio Power Amplifier IC 40W

### Overview

The STK404-000S series products are audio power amplifier hybrid ICs that consist of optimally-designed discrete component power amplifier circuits that have been miniaturized using SANYO's unique insulated metal substrate technology (IMST). The adoption of a newly-developed low thermal resistance substrate allows this series of devices to be provided in miniature packages significantly more compact than earlier SANYO products with similar specifications.

### Features

- Series of pin compatible power amplifiers ranging from 45W to 180W (10%/1kHz) devices. The same printed circuit board can be used depending on the output power grade.
- Miniature packages
  - 30W to 40W (THD=0.4%, f=20Hz to 20kHz); 44.0mm × 25.6mm × 8.5mm \*
  - 50W to 80W (THD=0.4%, f=20Hz to 20kHz); 46.6mm × 25.5mm × 8.5mm \*
  - 100W to 120W (THD=0.4%, f=20Hz to 20kHz); 59.2mm × 25.5mm × 8.5mm \*

\*: Not including the pins.

- Output load impedance:  $R_L=6\Omega$
- Allowable load shorted time: 0.3 seconds
- Supports the use of standby, muting, and load shorting protection circuits.

### Series Organization

These products are organized as a series based on their output capacity.

Item	Type No.						
	STK404-050S	STK404-070S	STK404-090S	STK404-100S	STK404-120S	STK404-130S	STK404-140S
Output 1 (0.4%/20Hz to 20kHz)	30W	40W	50W	60W	80W	100W	120W
Output 2 (10%/1kHz)	45W	60W	80W	90W	120W	150W	180W
Maximum supply voltage (6Ω)	±37V	±43V	±46V	±51V	±59V	±64V	±73V
Recommended supply voltage (6Ω)	±26V	±30V	±32V	±35V	±41V	±45V	±51V
Remarks	Built-in thermal protection circuit						
Package	44.0mm × 25.6mm × 8.5mm		46.6mm × 25.5mm × 8.5mm			59.2mm × 25.5mm × 8.5mm	

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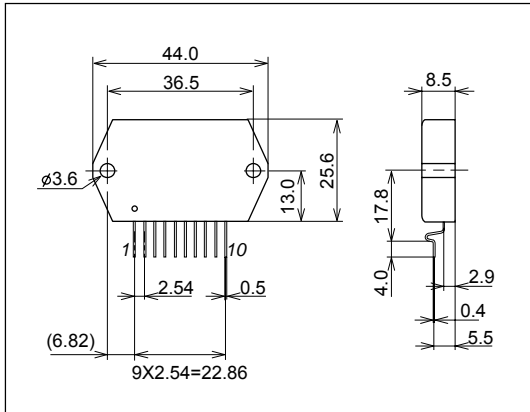
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Package Dimensions

unit : mm  
4203



Specifications

Maximum Ratings at  $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage (Quiescent)	$V_{CC \text{ max}(0)}$		$\pm 46$	V
Maximum supply voltage	$V_{CC \text{ max}(1)}$	$R_L = 6\Omega$	$\pm 43$	V
Thermal resistance	$\theta_{j-c}$	Per power transistor	2.6	$^\circ\text{C}/\text{W}$
Junction temperature	$T_{j \text{ max}}$	Both the $T_{j \text{ max}}$ and the $T_c \text{ max}$ conditions must be met.	150	$^\circ\text{C}$
IC substrate operating temperature	$T_c \text{ max}$		125	$^\circ\text{C}$
Storage temperature	$T_{stg}$		-30 to +125	$^\circ\text{C}$
Allowable load shorted time *3	$t_s$	$V_{CC} = \pm 30\text{V}$ , $R_L = 6\Omega$ , $f = 50\text{Hz}$ , $P_O = 40\text{W}$	0.3	s

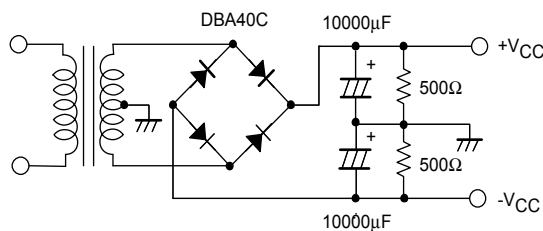
Operating Characteristics at  $T_c = 25^\circ\text{C}$ ,  $R_L = 6\Omega$  (noninductive load),  $R_g = 600\Omega$ ,  $V_G = 30\text{dB}$

Parameter	Symbol	Conditions *1				Ratings			Unit	
		$V_{CC}(\text{V})$	$f(\text{Hz})$	$P_O(\text{W})$	THD(%)	min	typ	max		
Output power	$P_{O(1)}$	$\pm 30.0$	20 to 20k		0.4	40			W	
	$P_{O(2)}$	$\pm 30.0$	1k		10		60			
Frequency characteristics	$f_L, f_H$	$\pm 30.0$		1.0		+0 -3dB	20 to 20k		Hz	
Input impedance	$r_i$	$\pm 30.0$	1k	1.0			55		$k\Omega$	
Output noise voltage *2	$V_{NO}$	$\pm 36.0$				$R_g = 10k\Omega$	1.2		mVrms	
Quiescent current	$I_{CCO}$	$\pm 36.0$				No load		50	mA	
Neutral voltage	$V_N$	$\pm 36.0$					-100	0	+100	mV

Notes: 1. Unless otherwise noted, a constant-voltage supply must be used during inspection.

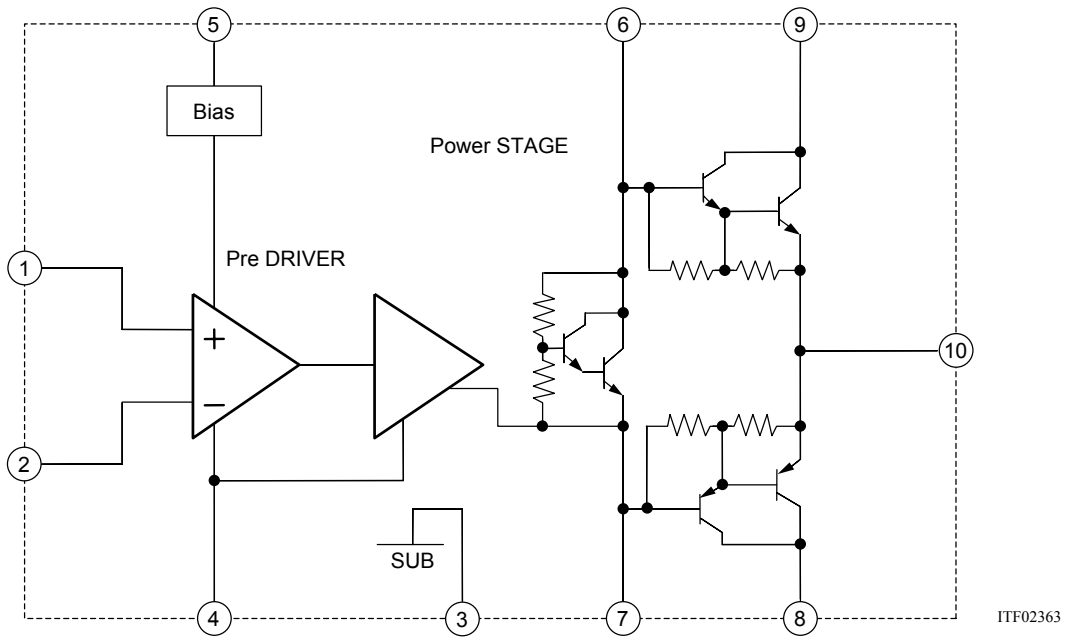
- The output noise voltage values shown are peak values read with a VTVM. However, an AC stabilized (50Hz) power supply should be used to minimize the influence of AC primary side flicker noise on the reading.
- Use the transformer power supply circuit shown in the figure below for allowable load shorted time measurement and output noise voltage measurement. This IC is designed assuming that applications will provide a power cut-off or other load-shorting protection function that is activated within 0.3 seconds of the load being shorted.

Designated Transformer Power Supply (RP-25 equivalent)

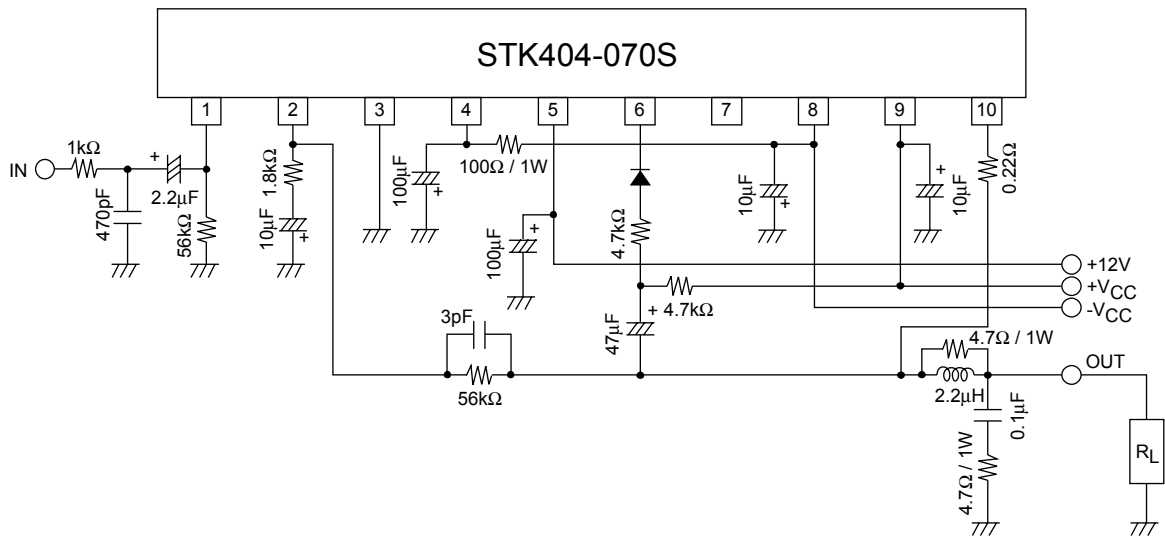


# STK404-070S

## Internal Equivalent Circuit



## Sample Application Circuit



### Thermal Design Example

If we define Pd, the total power dissipation on the board when this hybrid IC is in operation, the heat sink thermal resistance,  $\theta_{c-a}$ , is determined as follows:

Condition 1: The hybrid IC substrate temperature Tc must not exceed 125°C.

$$P_d \times \theta_{c-a} + T_a < 125^\circ\text{C} \dots\dots\dots (1)$$

Ta: Guaranteed ambient temperature for the end product.

Condition 2: The junction temperature Tj of each transistor must not exceed 150°C.

$$P_d \times \theta_{c-a} + P_d/N \times \theta_{j-c} + T_a < 150^\circ\text{C} \dots\dots\dots (2)$$

N: Number of power transistors

$\theta_{j-c}$ : Thermal resistance per power transistor

We take the power dissipation in the power transistors to be Pd evenly distributed across those N power transistors.

If we solve for  $\theta_{c-a}$  in equations (1) and (2), we get the following inequalities:

$$\theta_{c-a} < (125 - T_a)/P_d \dots\dots\dots (3)$$

$$\theta_{c-a} < (150 - T_a)/P_d - \theta_{j-c}/N \dots\dots\dots (4)$$

The value that satisfies both of these inequalities at the same time is the required heat sink thermal resistance value.

Example:

For actual music signals, it is usual to use a Pd of 1/8 of P<sub>O</sub> max, which is the power estimated for continuous signals in this manner. (Note that depending on the particular safety standard used, a value somewhat different from the value of 1/8 used here may be used.)

When V<sub>CC</sub> = ±30V and R<sub>L</sub> = 6Ω, we get the following expression for the total power dissipation on the board, Pd:

$$P_d = 20\text{W (when } 1/8 P_O \text{ max is } 5.0\text{W)} \dots\dots\dots (5)$$

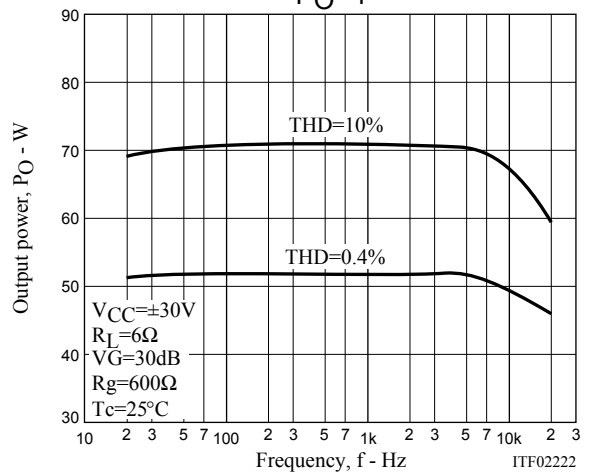
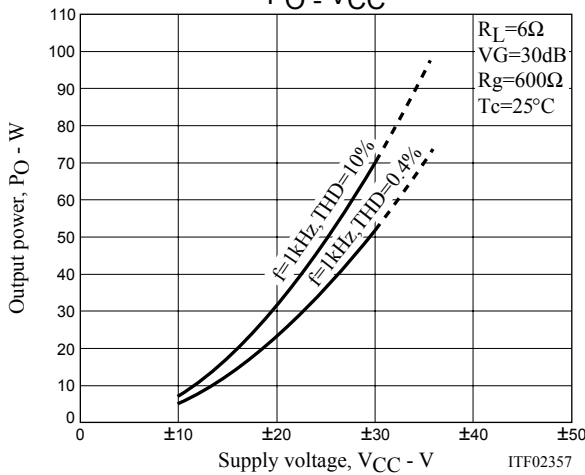
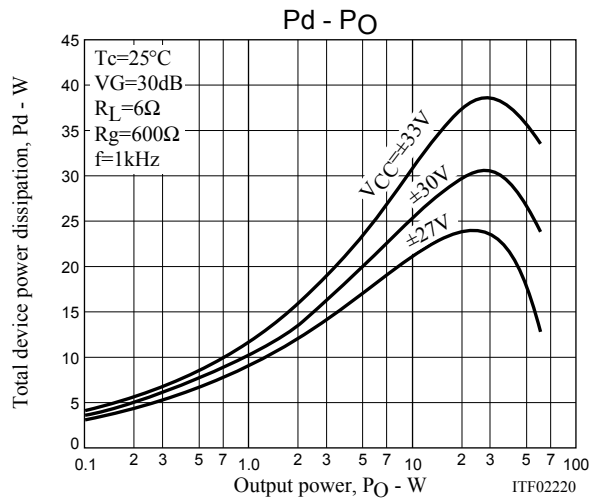
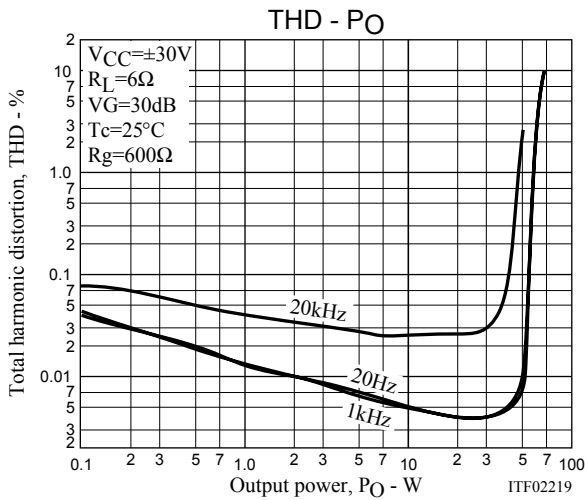
The number, N, of power transistors in the hybrid IC's audio amplifier block is 2. Since the thermal resistance,  $\theta_{j-c}$ , per transistor is 2.6°C/W, the required heat sink thermal resistance,  $\theta_{c-a}$ , for a guaranteed ambient temperature Ta of 50°C will be as follows:

$$\text{From inequality (3): } \theta_{c-a} < (125 - 50)/20 = 3.75 \dots\dots\dots (6)$$

$$\text{From inequality (4): } \theta_{c-a} < (150 - 50)/20 - 2.6/2 = 3.70 \dots\dots\dots (7)$$

Therefore, the thermal resistance that satisfies both of these expressions (6 and 7) at the same time is 3.70°C/W.

Note that this thermal design example assumes the use of a constant-voltage power supply, and is only provided as an example for reference purposes. Thermal designs must be tested in an actual end product.



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